Multiphoton processes in microwave photoresistance of 2D electron system

M . A . Zudov $^{1;2}$ and R . R . D u^1

¹Department of Physics, University of Utah, Salt Lake City, Utah 84112

²School of Physics and Astronom y, University of M innesota, M inneapolis, M innesota 55455

L.N.Pfei er and K.W.West

Bell Laboratories, Lucent Technologies, Murray Hill, New Jersey 07974

We extend our studies of m icrow ave photoresistance of ultra-high m obility two-dimensional electron system (2DES) into the high-intensity, non-linear regime employing both m onochrom atic and bichrom atic radiation. Under high-intensity m onochrom atic radiation ! we observe new zero-resistance states (ZRS) which correspond to rational values of " = $!=!_c$ (!_c is the cyclotron frequency) and can be associated with multiphoton processes. Under bichrom atic radiation !₁;!₂ we discover new resistance m inimum, possibly a precursor of bichrom atic ZRS, which seem s to originate from a frequency mixing process, !₁ + !₂. These notings indicate that multiphoton processes play important roles in the physics of non-equilibrium transport of m icrow ave-driven 2DES, and suggest new directions for theoretical and experimental studies.

PACS num bers: 73.40.-c, 73.43.-f, 73.21.-b

Intense current interest to millimeterwave photoconductivity of two-dimensional electron systems (2DES) was triggered by the discovery of microwave-induced resistance oscillations (MIRO)^{1,2} and zero-resistance states (ZRS),^{3,4} emerging in ultra-high mobility sam – ples at weak magnetic elds and low temperatures. While a great deal of attention has been paid both experimentally,^{5 19} and theoretically^{7;20 49} In particular, some recent experimental results appear to challenge existing theories.^{17,18} To advance our understanding of the phenomena we explore new experimental regime of high-intensity microwave (MW) radiation.

Phenom enologically, M IRO appear due to oscillatory m icrow ave photoresistance (PR), $R^{!} = R^{!} R^{0}$, which (i) is a periodic function in inverse magnetic eld, 1=B with a period given by " = $!=!_{c}$, where !=2 f and $!_{\rm C} = eB = m$ are m icrowave and cyclotron frequency, respectively, (ii) can take both positive (maxima) and negative (m in in a) values depending on ", and (iii) can approach the background dark resistance by absolute value under certain experim ental conditions. A lthough one could expect appearance of negative resistance at som e of the M IRO m in in a, experiments (and theory²²) usually (see, however Ref.10) show that 2DES instead exhibits ZRS, as the resistance saturates close to zero. Since the resistance maxima (+) and minima () appear in pairs⁹ situated roughly symmetrically about cyclotron resonance harm onics, i.e., " j i, they are com monly associated with an integral j (", j). AllZRS reported to date were observed at

 $"_{j} = j + _{j}; j = 1;2;3; ...$ (1)

where j is experimentally found to be 0 < 1=4.

The work reported here was provoked by peculiar photoresistance features far from integral", which were rst noticed in experiments on moderate mobility samples.¹ In particular, prominent resistance maximum and minimum were observed about " 1=2 at f = 45 GHz.¹ Later experiments con med this observation^{7,10,16} and even reported features close to other rational values of " j=m, e.g. 3/2, 5/2, and 2/3.^{4,9} It was proposed,⁹ that these features originate from two-(m = 2) and threephoton (m = 3) processes; here, an electron absorbs m photons to jmp j Landau level spacings. Moreover, it was noticed that the most readily detectable multiphoton structure at " 1=2 can develop a peak com parable in magnitude to the integral at " 1.⁹ Therefore, it is natural to ask if appropriate experimental conditions can be reached for multiphoton minim a to evolve into ZRS.New ZRS would appear in accordance with an analog of Eq. (1), generalized to incorporate multiphoton processes:⁹

$$\mathbf{T}_{j}^{(m)} = \frac{j}{m} + j^{(m)};$$
 (2)

Here m is the number of photons involved in a process and, therefore, such ZRS can be associated with a ratio j=m ($\mathbf{w}_{i}^{(m)}$ j=m).

On general basis, one expects that multiphoton ZRS would require much higher radiation intensities and, as such, would be di cult to detect. A long this line, signi cant experimental advantages are of ered by low ering microw ave frequency. First of all, low er frequency ensures single-mode operation of the waveguide which guarantees higher local intensity at the sample center. Second, low er frequency results in higher photon ux which scales with the inverse of the photon energy. Finally, low frequency moves the strongest two-photon feature $(\mathbf{m}_1^{(2)} = 1=2)$ out of the strong Shubnikov-de H aas regime where photoresponse becomes relatively weak.¹⁵

In this paper we report on transport studies of ultraclean 2DES under intense m icrowave irradiation, where the system reveals characteristically new features in photoresistance spectrum. The most prominent are new zero-resistance states em erging about rational values of ". W hile more pronounced rational ZRS are situated close to half-integers, e.g. two-photon $"_1^{(2)} = 1 = 2$, $"_3^{(2)} = 3 = 2$, we also observe form ation of a three-photon ZRS in the vicinity of $"_2^{(3)} = 2 = 3$. O ther interesting observations include reverse power dependence of the resistance peaks, accompanied by peak narrowing and phase reduction, as well as dramatic suppression of the magnetoresistance at " < 1=2. Finally, under bichromatic (frequencies $!_1;!_2$) MW radiation we detect a new resistance m inimum which seems to originate from a frequency mixing process, $!_1 + !_2$, and possibly presents the rst experimental support for bichromatic ZRS.

Our sample was cleaved from a MBE -grown, symmetrically doped A lo:24 G ao:76 A s/ G aA s/A lo:24 G ao:76 A s quantum well structure. A fter brief illum ination with visible light at low tem perature, electron m obility, and density, n_e saturated at 2 10⁷ cm²/Vs and 3:6 10^{11} cm², respectively. Experiment was performed in a toploading ³H e refrigerator equipped with a superconducting solenoid. Form onochrom atic experiments we employ a lower frequency (f = 27 GHz) m icrowave source to ensure single-mode operation of the WR-28 waveguide used to deliver radiation down to the sample. W ith microw aves, the tem perature of the coolant was in the range between 1.1 K and 1.8 K depending on the microwave intensity. U sing this tem perature rise we estim ate that the totalm icrow ave power at the bottom ange of the waveguide was from 2 to 12 times larger than in our previous (100 W) studies.⁴ At these intensities one can anticipate potential com plications associated with recti cation of m icrowave radiation on sample contacts. To check against such e ects we have veri ed that measured voltages remain linear with the excitation current and that zero- eld voltage does not depend on microwave intensity. To implement bichromatic MW experiments, EM waves from two Gunn diodes tuned to distinct frequencies ($f_1 = !_1=2 = 31 \text{ GHz}$, $f_2 = !_2=2 = 47 \text{ GHz}$) were combined using a hybrid \T "mounted on the top ange of the waveguide. A 11 the data presented here were recorded using conventional quasi-dc lock-in technique (1 A, 17 Hz), at a constant tem perature, under continu-

A, 1/Hz), at a constant temperature, under continuous MW illum ination of xed frequency and power, while sweeping the magnetic eld.

In Fig.1 we show the evolution of photoresistance with increasing MW intensity at f = !=2 = 27 GHz. Here, the intensity is varied by adjusting the attenuator in 2 dB steps starting with -8 dB (top trace) down to 0 dB (bottom trace). In the top, lowest intensity trace, we easily identify the most prominent two-photon feature corresponding to $"_1^{(2)}$ 1=2 (see arrow). A swe decrease attenuation to -6 dB another two-photon minimum at "⁽²⁾ 3=2 (see arrow) appears in magnetoresistance. The next trace, -4 dB, reveals yet another minimum in the vicinity of $"^{(3)}_2$ 2=3 (see arrow), which, according to Eq. (2), corresponds to a three-photon process. M ost rem arkably, we observe for the st time that both twophoton m in im a now develop into well-resolved ZRS, corresponding to rational $"_1^{(2)}$ 1=2 and $"_{3}^{(2)}$ 3=2. All

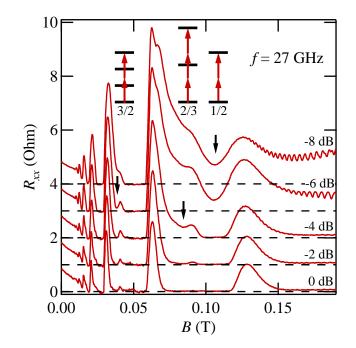


FIG.1: [color online] M agnetoresistance under m icrow ave illum ination of f = !=2 = 27 GHz, for selected radiation intensities. Traces are vertically o set for clarity and are m arked by attenuation. Vertical downward arrows m ark the positions of oscillations m inim a corresponding to rational values of " 3=2, 2/3, and 1/2, from left to right, which develop into new ZRS with increasing intensity. Insets illustrate virtual multiphoton processes responsible for these features at rational ". At B > 0:15 T non-resonant suppression of resistance is observed.

observed multiphoton features are accompanied by insets which schematically illustrate the relation between Landau level spacings and the photon energy at corresponding ratios. Increasing the intensity further, at -2 dB, we observe form ation of a three-photon ZRS at $"_2^{(3)}$ 2=3. At full m icrow ave power, 0 dB, this three-photon ZRS merges with the strongest two-photon ZRS at $"_1^{(2)}$ 1=2. A nother interesting feature of the data is the radiation-induced suppression of resistance at B > 0:15 T (c.f., " < 0:4 in Fig.2(a)), where the resistance drops by a factor of 20 with increasing m icrow ave power.

Careful exam ination of the second-order resistance m inim a (i.e., at B 0.028 T) reveals sm all negative resistance value (0.04 0 hm s), which falls beyond the noise level. W hile this value remains unchanged at all m icrowave intensities studied, it appears to be similar to the features reported by W illett.¹⁰ The origin of this sm all negative resistance is unclear, but it is unlikely to be caused by the voltage contacts, since, in the sam eR_{xx} trace clear zeros are observed near $\mathbf{u}_{1}^{(1)}$ and $\mathbf{u}_{1}^{(2)}$.

In Fig.2 we plot the lowest (-8 dB), the middle (-4 dB), and the highest (0 dB) intensity traces as a function of ". In panel (a) we concentrate on the regime of " 1, which includes features at " 1=2;2=3;1, while panel (b) focuses on features at " 3=2;2. P lotted without

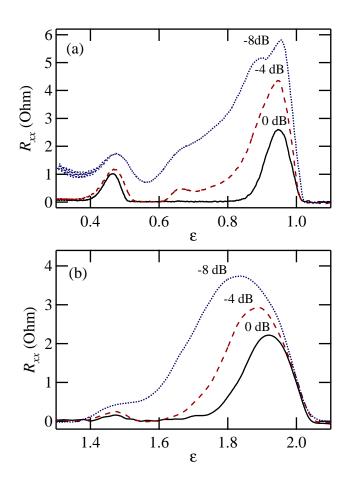


FIG.2: [color on line] M agnetoresistance under m icrow ave illum ination of f = 27 G H z as a function of ", at selected attenuations of -8 dB (dotted [blue] line), -4 dB (dashed [red] line), and 0 dB (solid [black] line), as m arked. Panels (a) and (b) show evolution of photoresistance features at " 1=2;2=3;1and " 3=2;2, respectively.

o set, the data reveal that all resistance peaks actually dim inish with increasing power. This strongly non-linear behavior is the characteristic property of the high intensity regime studied here. With the power increase by roughly a factor of six, the resistance of the rst (second) order peak decreases by 55 (40)%, while the two-photon **"**(2) 1=2 peak seems to saturate. This is in contrast to our earlier low er-intensity, higher-frequency studies⁴ where the PR maxima increased roughly linearly with MW intensity. As we already mentioned, the temperature of the coolant was increasing with microwave inten-1.1 K up to 1.8 K.Observed reduction of sity, from the resistance peaks, however, cannot be attributed to the tem perature increase alone since at the same time ZRS becom e stronger.

A nother in portant aspect of the data shown in F ig.2 is the narrowing of the integral resistance peaks at $"_1^{(1)}; "_2^{(1)}$ with increasing power. We notice that in both cases narrowing occurs at the expense of the lower-" shoulder, while another edge of the peak is a ected only slightly, if at all. This behavior may be due to multiphoton pro-

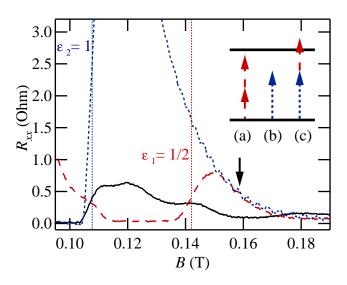


FIG. 3: [color online] M agnetoresistance under monochromatic $f_1 = 31 \text{ GHz}$ (dashed [red] line), $f_2 = 47 \text{ GHz}$ (dotted [blue] line) and bichromatic, $f_1 = 31 \text{ Ghz}$ and $f_2 = 47 \text{ GHz}$, (solid [black] line). Vertical dashed [red] and dotted [blue] lines mark $"^{(2)}_{1_1} = 1=2$ and $"^{(1)}_{1_2} = 1$, respectively. Vertical downward arrow at 0.16 T mark the position where deep bichromatic minimum is formed. Inset illustrates three possible processes, from left to right, involving (a) two f_1 photons, (b) one f_2 photon, and (c) one f_1 and one f_2 photon and thus correspond to positive photoresistance, (c) results in over-promoting an electron resulting in negative photoresistance.

cesses com ing into play with increasing power, which induce new rationalm in in a resulting in narrow er integral peaks. However, there is a noticeable di erence in the evolution of $\mathbf{w}_1^{(1)}$ and $\mathbf{w}_2^{(1)}$ resistance peaks. W hile the position of the $\mathbf{u}_1^{(1)}$ peak does not experience any signi cant variation, staying at $"_1^{(1)}$ 0:95, $"_2^{(1)}$ peak m oves closer to the second harm onic of the cyclotron resonance with increasing power. In fact, the phase $\binom{1}{2}$ of this peak decreases roughly by a factor of two in this range of microwave intensity, from 0.16 at -8 dB down to 0.08 at 0 dB.W ith increasing m icrowave intensity, resistance peaks become more symmetric and it is interesting to compare their widths. The width of the peaks at the highest m icrow ave power, $"_2^{(1)}$ 0.158, $"_1^{(1)}$ 0:086, **"**(2) and 0:056, increases roughly linear with ".

Now we turn to the discussion of our bichrom atic experiment, where we employ microw ave radiation provided by two MW sources of distinct frequencies, $f_1 = !_1=2 = 31 \text{ GHz}$ and $f_2 = !_2=2 = 47 \text{ GHz}$. Detailed results of bichrom atic experiments not dealing with multiphoton processes will be published elsewhere.⁵⁰ The issue that we address here is the bichrom atic response of the system in the regime of relatively high magnetic elds, where $!_C > !_1; !_2$. From the results of monochrom atic experiments described above, we expect the form ation of ratio-

naltwo-photon peak $"^{(2)}_{!_1}$ 1=2, which is easily identi ed in Fig.3 at 0.15 T. This peak will then overlap with the higher-B tail of the fundamental $"^{(1)}_{12}$ 1 peak induced by higher frequency $!_2$. We observe that while the m onochrom atic resistances alm ost coincide to the right of the two-photon $!_1$ peak, the bichrom atic resistance is strongly suppressed. In fact, observed bichrom atic resistance, $R_{xx}^{!_1!_2}$ is almost one order of magnitude lower than m on och rom at ic resistances $R_{xx}^{!_1} = R_{xx}^{!_2}$, which m ight indicate formation of a new ZRS. This new minimum only appears under bichrom atic radiation and therefore its origin must be related to a process involving both m icrow ave photons. W e speculate that possible frequency m ixing m ight in uence the resonant condition w hich governs the sign of PR, thus converting PR maximum to a m in im um. For further discussion, we refer to the inset of Fig.3 where the relation between the cyclotron gap and m icrow ave quanta is graphically presented at B = 0.16T.Both monochromatic $!_1$ two-photon (a) and $!_2$ onephoton (b) transitions under-promote an electron, and, therefore, correspond to a positive PR. Adding one of the $!_1$ with one $!_2$ photon changes the situation and an electron is now over-prom oted and produces negative PR, possibly leading to new ZRS.

In summary, we have studied experimentally mi-

- ¹ M.A.Zudov, R.R.Du, J.A.Simmons and J.L.Reno, Phys.Rev.B 64, 201311(R) (2001).
- ² P.D.Ye, L.W. Engel, D.C.Tsui, J.A.Simmons, J.R. Wendt, G.A.Vawter and J.L.Reno, Appl. Phys. Lett. 79, 2193 (2001).
- ³ R.G.Mani, J.H.Smet, K.von Klitzing, V.Narayanamurti, W.B.Johnson and V.Umansky, Nature 420, 646 (2002).
- ⁴ M.A.Zudov, R.R.Du, L.N.Pfei er and K.W.West, Phys.Rev.Lett. 90, 046807 (2003).
- ⁵ R.G.Mani, J.H.Smet, K.von Klitzing, V.Narayanamurti, W.B.Johnson and V.Umansky, Phys.Rev.B 69, 193304 (2004).
- ⁶ C. L. Yang, M. A. Zudov, T. A. Knuuttila, R. R. Du, L.N. Pfei er and K.W. West, Phys. Rev. Lett. 91, 096803 (2003).
- ⁷ S.I.Dorozhkin, JETP Lett. 77, 577 (2003).
- ⁸ R.G.Mani, V.Narayanamurti, K.von Klitzing, J.H. Smet, W.B.Johnson and V.Umansky, Phys.Rev.B 70, 155310 (2004).
- ⁹ M.A.Zudov, Phys.Rev.B 69, 041304(R) (2004).
- ¹⁰ R.L.W illett, L.N.P fei er and K.W.W est, Phys.Rev. Lett. 93, 026804 (2004).
- ¹¹ R.G.Mani, J.H.Smet, K.von Klitzing, V.Narayanamurti, W.B.Johnson and V.Umansky, Phys. Rev. Lett. 92, 146801 (2004).
- ¹² S. A. Studenikin, M. Potem ski, P. T. Coleridge, A. S. Sachrajda and Z. R. W asilew ski, Solid State Commun. 129, 341 (2004).
- ¹³ R.G.Mani, V.Narayanamurti, K. von Klitzing, J.H. Smet, W.B.Johnson and V.Umansky, Phys.Rev.B 69, 161306(R) (2004).

crowave photoresistance of high-mobility 2DES in the high-intensity regime. In monochromatic experiments, we have detected new zero-resistance states corresponding to rational values of ", i.e., 1=2, 3=2, and 2=3, which we associate with two-and three-photon processes. Formation of these new ZRS with increasing power is com plemented by diminishing height, width, and phase of the resistance peaks, as well as dram atic reduction of the resistance at " < 0:4. Under bichrom atic MW radiation we observe strong suppression of resistance appear-0:16 T when monochromatic " $^{(1)}_{!2}$ ing at B 1 and "⁽²⁾ 1=2 peaks overlap. This suppression possibly originates from a frequency mixing process, $!_1 + !_2$, which alters the resonant condition, and m ight indicate a form ation of a new, bichrom atic ZRS.Taken together, these results dem onstrate that multiphoton processes both in m onochrom atic and bichrom atic setups can signi cantly contribute to the photoresistance of the 2D E S and, therefore, should be appropriately addressed in future theoretical and experim ental studies.

W e would like to thank M.E.Raikh, F.von Oppen, A.M irlin, and A.Stern for their interest and helpful discussions. This work is supported by DARPA QuIST and NSF DMR-0408671.

- ¹⁴ A.E.Kovalev, S.A.Zvyagin, C.R.Bowers, J.L.R.c and J.A.Simmons, Solid State Commun. 130, 379 (2004).
- ¹⁵ S. A. Studenikin, M. Potem ski, A. Sachrajda, M. Hilke, L. N. Pfei er and K. W. West, Phys. Rev. B 71, 245313 (2005).
- ¹⁶ S.I.D orozhkin, J.H. Sm et, V.Um ansky and K.von Klitzing, Phys. Rev. B 71, 201306 (R) (2005).
- ¹⁷ C.L.Yang, R.R.Du, L.N.P fei er and K.W. West condm at/0504715 (unpublished).
- ¹⁸ J. H. Sm et, B. Gorshunov, C. Jiang, L. Pfei er, K. West, V. Um anksy, M. D ressel, R. M eisels, F. Kuchar and K. von Klitzing, Phys. Rev. Lett. 95, 116804 (2005).
- ¹⁹ R.G.Mani, Phys. Rev. B 72, 075327 (2005).
- ²⁰ V.Shikin, JETP Lett. 77, 236 (2003).
- ²¹ A.C.Durst, S.Sachdev, N.Read and S.M.Girvin, Phys. Rev.Lett. 91, 086803 (2003).
- ²² A.V.Andreev, I.L.A leiner and A.J.M illis, Phys. Rev. Lett. 91, 056803 (2003).
- ²³ J.Shiand X.C.X ie, Phys. Rev. Lett. 91, 086801 (2003).
- ²⁴ A.A.K oulakov and M.E.Raikh, Phys.Rev.B 68, 115324 (2003).
- ²⁵ F.S.Bergeret, B.Huckestein and A.F.Volkov, Phys.Rev. B 67, 241303 (R) (2003).
- ²⁶ J.C. Phillips, Solid State Commun. 127, 233 (2003).
- ²⁷ X.L.Leiand S.Y.Liu, Phys. Rev. Lett. 91, 226805 (2003).
- ²⁸ V. Ryzhii and V. Vyurkov, Phys. Rev. B 68, 165406 (2003).
- ²⁹ V.Ryzhü, Phys.Rev.B 68, 193402 (2003).
- ³⁰ M.G.Vavibv and I.L.A leiner, Phys. Rev. B 69, 035303 (2004).
- ³¹ D.-H. Lee and J. M. Leinaas, Phys. Rev. B 69, 115336 (2004).

- ³² A.F.Volkov and V.V.Pavlovskii, Phys. Rev.B 69, 125305 (2004).
- ³³ K.Park, Phys.Rev.B 69, 201301(R) (2004).
- ³⁴ I.A.Dm itriev, M.G.Vavilov, I.L.A leiner, A.D.M irlin and D.G.Polyakov, Phys. Rev. B 71, 115316 (2005).
- ³⁵ I.A.Dm itriev, A.D.M irlin and D.G.Polyakov, Phys. Rev.B 70, 165305 (2004).
- ³⁶ P.H.Rivera and P.A.Schulz, Phys. Rev. B 70, 075314 (2004).
- ³⁷ M. Torres and A. K unold, Phys. Rev. B 71, 115313 (2005).
- ³⁸ S.A.M ikhailov, Phys.Rev.B 70, 165311 (2004).
- ³⁹ M.G.Vavilov, I.A.Dm itriev, I.L.A leiner, A.D.M irlin and D.G.Polyakov, Phys. Rev. B 70, 161306 (R) (2004).
- ⁴⁰ C. Joas, M. E. Raikh and F. von Oppen, Phys. Rev. B 70, 235302 (2004).
- ⁴¹ V.Ryzhii, A.Chaplik and R.Suris, JETP Lett. 80, 363 (2004).
- $^{\rm 42}$ J.D ietel, L.I.G lazman, F.W .J.Hekking and F.von

Oppen, Phys. Rev. B 71, 045329 (2005).

- ⁴³ J. Inarrea and G. P latero, Phys. Rev. Lett. 94, 016806 (2005).
- ⁴⁴ J.Aliœa, L.Balents, M.P.A.Fisher, A.Param ekantiand L.Radzihovsky, Phys.Rev.B 71, 235322 (2005).
- ⁴⁵ T. Toyoda, M. Fujita, H. Koizum i and C. Zhang, Phys. Rev.B 71, 033313 (2005).
- ⁴⁶ A. Auerbach, I. Finkler, B. I. Halperin and A. Yacoby, Phys. Rev. Lett. 94, 196801 (2005).
- ⁴⁷ X.L.Leiand S.Y.Liu, Phys. Rev. B 72, 075345 (2005).
- ⁴⁸ I.A.Dm itriev, A.D.M irlin and D.G.Polyakov, Phys. Rev.Lett. 91, 226802 (2003).
- ⁴⁹ E.E. Takhtam irov and V.A. Volkov cond-m at/0506727 (unpublished).
- ⁵⁰ M.A.Zudov, R.R.Du, L.N.P fei er and K.W.W est (unpublished).